Scanning Microwave Microscope Mode

Application Note

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Introduction
Measuring electromagnetic properties of materials can provide insight into applications in many areas of science and technology, and increasingly, these properties need to be evaluated at the nanometer scale. Since electromagnetic properties, such as the dielectric constant, are ultimately related to a material’s molecular structure, correlating the detailed physical structure of a material with its electromagnetic properties is frequently more valuable than the knowledge of either alone.

Agilent Technologies’ Scanning Microwave Microscope (SMM) Mode is a new Scanning Probe Microscope (SPM) that combines the electromagnetic measurement capabilities of a microwave vector network analyzer (VNA) with the nanometer-resolution and Angstrom-scale positioning capabilities of an Atomic Force Microscope (AFM).

Microwave Vector Network Analyzer
The SMM uses Agilent’s VNA microwave vector network analyzer (Figure 1). Like all network analyzers, this VNA is a stimulus-response instrument, optimized for accurate and repeatable measurement of the response of a network or a device under test (DUT) to a known stimulus signal. This is in contradistinction to instruments such as the spectrum analyzer, which are usually configured as a receiver (only) of an unknown signal, and which do not include a source for a stimulus to be applied to the DUT.

A VNA has two operational modes: transmission and reflection. In the reflection (alternatively, transmission) mode, the VNA measures the magnitude and phase characteristics of the DUT.

The incident signal is generated and controlled inside the VNA; as a result, the ratios $R$ and $T$ are not merely relative, but referenced to the well-known, accurately quantified incident signal.

This measurement capability, delivered to the apex of an AFM tip makes the SMM the only SPM in its class, enabling calibrated, traceable measurements of electrical properties such as impedance and capacitance, with the high spatial resolution that is the hallmark of a well-designed, well-constructed AFM.

Figure 1. VNA (left) and AFM scanner and 5400 (right).

1 The main difference between a scalar network analyzer and a VNA is the ability of the VNA to make phase measurements.
by comparing the signal that reflects off (alternatively, transmits through) the device with the stimulus signal.\(^2\) Each mode enables measurement of several useful parameters. In the reflection mode, the VNA can measure (among other things) the impedance of the DUT.\(^3\) Scanning Impedance Microscopy is a major application of the SMM.

**Scanning Impedance Microscopy**

One of the most common applications of network analysis is measuring the impedance of a component, so as to evaluate if it matches the impedance of the other components with which it must interface in a network. Impedance measurement techniques in network analyzers have become quite advanced and refined.

The SMM uses the VNA in reflection mode for measuring the impedance of the “network” that includes the tip-sample interface.\(^4\) In the SMM, the DUT for the VNA consists of the AFM probe and the region of the sample immediately beneath the metal-coated AFM tip. One application of impedance measurement with SMM is scanning capacitance microscopy (SCM) of semiconductors. Here the AFM tip and the semiconductor sample form a metal-oxide-semiconductor (MOS) capacitor. (More on SCM later).

The incident microwave signal travels through a series of components before it reaches the tip-sample interface by means of a transmission line. The impedance mismatch between the transmission line and the DUT causes the incident microwave signal to partially reflect from the tip-sample interface back towards the stimulus signal source inside the VNA; this reflected signal is proportional to the impedance mismatch. The incident microwave signal and the reflected microwave signal together contain information about the impedance of the DUT. See “Sidebar” for more detail.

**Scanning Capacitance Microscopy**

Measuring the capacitance-to-ground (C) of the tip-sample interface, and its variation (dC/dV) with an applied AC bias (V=V_0 Sin[ωt]) is an important extension of atomic force microscopy (AFM) for the electrical characterization of semiconductors. It enables a two-dimensional mapping of the carrier density across different regions of a semiconductor, with applications in the failure analysis, characterization, modeling

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\(^2\) In some older model network analyzers, the stimulus signal was taken from a separate source. In Agilent’s VNA, the knowledge of the stimulus signal is excellent, because it is a (microwave) signal generated inside the VNA with high resolution and stability of both the amplitude and the frequency.

\(^3\) Impedance is the total resistance that a DUT presents to the flow of an AC signal at a given frequency.

\(^4\) The word network as used in “network analyzer” is generic and broadly defined. The origin of its usage (as it now relates to network analysis) goes back to the seminal work of the founders of Hewlett Packard Company, formerly the parent company of Agilent Technologies. Bill Hewlett and David Packard used the term network to refer to the electronic circuits they were using to test their first products, which started with signal generators! But as it is used today, the word network can for example apply to a liquid sample or a plastic sample or even a food sample as a DUT in network analysis.

\(^5\) S\(_{11}\) is one of four scattering parameters (S-Parameters), which are used to characterize the response of a DUT at high frequencies, in a way that is consistent with transmission line theory. All four S Parameters are ratios of voltage traveling waves entering and exiting the DUT. For more information, please visit Agilent’s website: http://wireless.agilent.com/networkanalyzers/pndemo.htm
and simulation of device performance, and also in the development of the semiconductor fabrication process.

Traditionally, a resonant capacitive sensor-based scanning capacitance microscopy (SCM) technique has been used to implement this type of AFM technique with some success. One of the main shortcomings of traditional SCM is the difficulty of making absolute measurements of the strength of the tip-sample electrical interaction; therefore, SCM images remain maps of the relative difference in carrier densities across the scanned area. For this reason, accomplishing the much coveted task of using SCM to reliably and repeatably extract numerical estimates for carrier densities in semiconductor devices remains elusive.

Agilent VNA hardware includes precision components for the calibration and performance verification of the instrument, thereby extending its applications to those that require calibrated, traceable, and absolute measurements of, for example, capacitance.

The SMM makes high-resolution, calibrated measurements of the capacitance-to-ground between an AFM tip and a semiconductor sample. This is achieved using an impedance transformer that places the DUT—directly across an external 50 Ω impedance, that is, parallel to it (Figure 3). In this way, the SMM operates the VNA with the sensitivity and resolution required to measure capacitance changes on the order of 0.1 aF across a 0.1 fF base capacitance. Furthermore, this impedance transformation is done at a location that is physically remote from the tip-sample interface, thereby facilitating mechanical design implementation.

The results of Agilent’s ADS Microwave Simulator for this setup (Figure 4) show that the VNA now operates with a resonant structure as its load, thus enabling it to measure minute changes in the value of the capacitance-to-ground for a MOS capacitor that consists of the metalized AFM tip, a semiconductor sample, and the oxide between them.

Spectroscopy with SMM

SMM brings the vast measurement capabilities of the VNA to expand AFM-based spectroscopy techniques for electromagnetic characterization, beyond anything that has been available in a commercial product so far. For example, power sweep and frequency sweep capabilities of the VNA are perfectly suited for characterizing the frequency response of a given location on a sample. Even the VNA’s most common methods for representing measurements, such as the Smith Chart, and the Linear Phase plot, open up a wide range of possibilities for spectroscopic techniques with AFM. In addition, the VNA supports and operates (directly on the instrument) numerous material characterization software packages from Agilent; these allow, for example, the measurement of the complex permittivity of a material.

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4 Spectroscopic techniques in AFM are conducted by disabling the AFM’s raster scanning, and interrogating the sample at the location of the AFM tip while sweeping a parameter across a range of its values; for example, the amplitude or the frequency of a signal applied to the tip or to the sample. For more information, please visit: http://cp.literature.agilent.com/litweb/pdf/5989-8215EN.pdf
Calibrated Measurements

Agilent’s VNA measurements are calibrated with Agilent’s “ECal,” the electronic calibration kits for fast, simple, accurate calibration of the instrument, including phase measurements. The instrument’s firmware makes the calibration a routine push-button task that completes within seconds.

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